



1.0A SURFACE MOUNT GLASS PASSIVATED RECTIFIER

Product Summary (@ TA = +25°C)

Vrrm (V)	lo (A)	VF(MAX) (V)	Ir(max) (μΑ)
1000	1	1.1	5

Description and Applications

The S1MWF is a rectifier packaged in the small form factor, low profile SOD123F (Type B) package. Providing high reverse breakage voltage, low reverse leakage current, and high surge current capability for standard rectification, this device is ideal for use in general rectification applications such as:

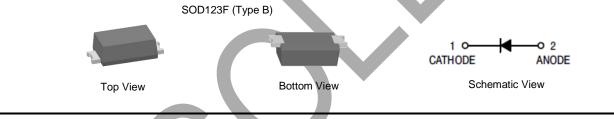
- Switching mode power supplies
- DC-DC converters
- AC-DC adaptors/chargers
- Mobile devices
- LED lighting

Features and Benefits

- Glass Passivated Die Construction
- Small Form Factor, Low Profile
- Surge Overload Rating to 30A Peak
- Low Reverse Leakage Current
- High Reverse Breakage Voltage
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Package: SOD123F
- Package Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Polarity: Cathode Band
- Weight: 0.018 grams (Approximate)



Ordering Information (Note 4)

Part Number	Baakaga	Packing		
Fait Nulliper	Package	Qty.	Carrier	
S1MWF-7	SOD123F (Type B)	3,000	Tape & Reel	

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

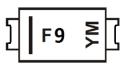
Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and

<1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

SOD123F (Type B)



 $\begin{array}{l} \mathsf{F9} = \mathsf{Product} \ \mathsf{Type} \ \mathsf{Marking} \ \mathsf{Code} \\ \mathsf{YM} = \mathsf{Date} \ \mathsf{Code} \ \mathsf{Marking} \\ \mathsf{Y} = \mathsf{Year} \ (\mathsf{ex:} \ \mathsf{K} = 2023) \\ \mathsf{M} = \mathsf{Month} \ (\mathsf{ex:} \ 9 = \mathsf{September}) \end{array}$

Date Code Key

Year	2014		2023	2024	2025	2026	2027	2028	2029	2030	2031	2032
Code	В		K	L	М	Ν	0	Р	R	S	Т	U
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic			Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		Vrrm Vrwm Vrm	1,000	V
RMS Reverse Voltage		V _{R(RMS)}	700	V
Average Rectified Output Current	@ T _T = +100°C	lo	1.0	А
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rate	ed Load	I _{FSM}	30	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance, Junction to Case (Note 5)	Rejc	8	°C/W
Typical Thermal Resistance Junction to Ambient (Note 5)	R _{0JA}	56	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

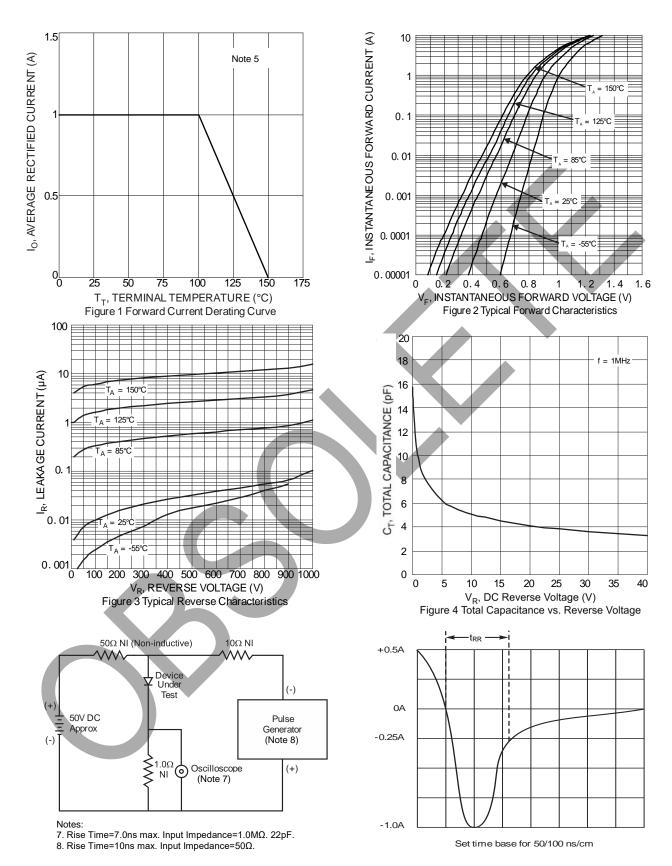
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 6)	V(BR)R	1,000		—	V	I _R = 5μA
Forward Voltage Drop	VF	-	0.95 0.85 1.0 0.9	1.1 1.0 —	V	$I_{F} = 1A, T_{J} = +25^{\circ}C$ $I_{F} = 1A, T_{J} = +125^{\circ}C$ $I_{F} = 2A, T_{J} = +25^{\circ}C$ $I_{F} = 2A, T_{J} = +125^{\circ}C$
Leakage Current (Note 6)	IR	-	0.15 6	5.0 100	μA	V _R = 1,000V, T _J = +25°C V _R = 1,000V, T _J = +125°C
Reverse Recovery Time	trr	—	1.5	3.0	μs	I _F = 0.5A, I _R = 1.0A, I _{RR} = 0.25A
Total Capacitance	Ст	—	7	_	pF	$V_R = 4.0 V_{DC}$, f = 1MHz

 Device mounted on FR-4 substrate, 1.0" x 1.0", 2oz, single-sided, PC boards with 0.2" x 0.25" copper pad.
Short duration pulse test used to minimize self-heating effect. Notes:



OBSOLETE – PART DISCONTINUED

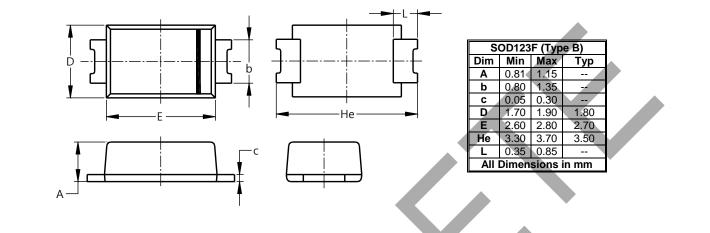




Package Outline Dimensions

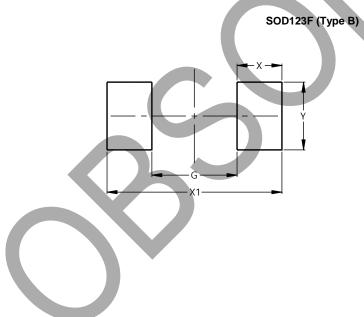
Please see http://www.diodes.com/package-outlines.html for the latest version.

SOD123F (Type B)



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
G	1.90
Х	1.00
X1	3.90
Y	1.50



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